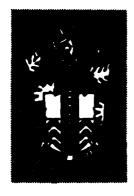


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# RSRE MEMORANDUM No. 3479

# ROYAL SIGNALS & RADAR ESTABLISHMENT

DETERMINATION OF OXYGEN AND CARBON IN SILICON WAFERS

Author: R W Series

PROCUREMENT EXECUTIVE, MINISTRY OF DEFENCE, R S R E MALVERN, WORCS.



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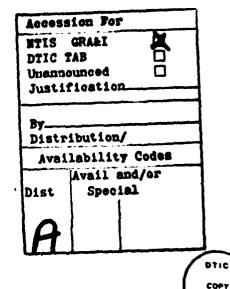
Date:

August 1982

#### SUMMARY

Possibilities for the use of a dispersive infrared spectrophotometer to determine the oxygen and carbon content of device quality silicon wafers have been examined. A novel approach to the analysis of the spectra based on a curve fitting method has been employed. This has been shown to provide very minimized approach to the analysis of the spectra based on a curve fitting method has been employed. This has been shown to provide very method rejection of interferences due to absorptions cuased by precipitates present in heat treated material. Single instrument precisions for measurements on 350 m device quality wafers of better than 10% for oxygen and + 2 x 1016 atom cm<sup>-3</sup> for carbon with no correcton for wafer backsurface finish are reported.

+or-2 x 10 to the 16th power /ce



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# RSRE MEHORANDUM No 3479

# DETERMINATION OF OXYGEN AND CARBON IN SILICON WAFERS

#### R W Series

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#### 1 INTRODUCTION

This memorandum summarises results of a study conducted at RSRE into development of methods suitable to determine the oxygen and carbon content of device quality silicon wafers using measurements based on local mode infrared absorption at 1106 cm<sup>-1</sup> and 605 cm<sup>-1</sup>. The equipment consists of a Perkin Elmer 5808 dispersive ratio recording infrared spectrophotometer and a model 3500 data station. All computing was carried out using standard BASIC as supplied with the data station. The emphasis of the work has been to develop quick, non destructive methods which are as insensitive as possible to surface finish and other interferences. In keeping with these constraints no attempt has been made to use low temperature measurements or special sample preparation techniques. Two differing mathematical methods have been used to analyse the spectra. The first is based on integrated area measurements and the second on a curve fitting method developed at RSRE. While there is little to chose between the two, the curve fitting method offers improved performance for difficult and heat treated samples. The method has been routinely used at RSRE for over a year with no problems.

Copies of the program, which include provision for fully automatic control of the spectrophotometer are available on request.

## 2 CONVERSION OF TRANSMITTANCE TO ABSORBANCE

When using any analytic method to analyse the spectra it is necessary first to convert the measured transmittance to absorbance. As shown in reference 1 the approximations commonly used may lead to errors in excess of 15% when thin wafers are measured. The effects of various approximations for the conversion of transmittance to absorbance have therefore been examined.

The transmission through a sample with both surfaces polished may be written (neglecting interference effects):

$$T = (1-R)^2 \exp(-a)/(1-R^2 \exp(-2a))$$
 (2.1)

where R is the reflection coefficient and a the absorbance.

To a first approximation

$$a = -ta(T) + 2ta(1-R)$$
 (2.2)

which is the most commonly used relationship. A much better approximate solution is

$$a = -ta(T) - ta(\frac{(1-R^2)}{(1-R)^2}) + R^2 (1-T^2)(\frac{(1-R^2)}{(1-R)^2})^2$$
 (2.3)

With this approximation the errors are less than 4% for all values of a.

With samples in both reference and sample beams the corresponding equations are

$$\mathbf{A} - \mathbf{a} = -\mathbf{t}\mathbf{a}(\mathbf{T}) \tag{2.4}$$

$$8 - a = -ta(T) + R^2 \exp(-28)(T^2 - 1)$$
 (2.5)

where I is the absorbance in the reference bean.

Physically the difference between the approximations corresponds to the difference between light passing once through the sample, and account being made of multiple reflections within the sample (fig 1).





FIGURE 1

For well polished samples approximation 2-3 and 2-5 are to be preferred, but for waters with heavy back surface damage it is possible that reflection at the rough surface is suppressed such that 2-2 and 2-4 provide better descriptions. This point can only be resolved by experiment as discussed later.

#### 3 INTEGRATED AREA MEASUREMENT METHOD

The spectre are scanned and converted to absorbance. Linear baselines are fitted to the oxygen band and the carbon/silicon band. The integrated areas in the range 1120-1000 cm<sup>-1</sup> for the oxygen band, 630-610 cm<sup>-1</sup> for the lattice absorption, 610-995 cm<sup>-1</sup> for the carbon absorption are then used to compute thickness, exygen and carbon difference between the sample and reference.

I - integrated area 1120-1090 cm<sup>-1</sup> (corrected for baseline)

I - integrated area 630-610 cm<sup>-1</sup> (corrected for baseline)

I - integrated area 610-995 cm<sup>-1</sup> (corrected for baseline)

$$R_1 = C_0 \Delta T + C_1 \text{ (T-AT) (0)}$$
 (3.1)

$$E_2 - C_2\Delta T + C_3$$
 (T-AT) [C] (3.2)

$$z_3 - c_4 a t - c_5$$
 (T-at) [C] (3.2)

where  $C_{\Omega}$  . It metrix absorption per unit thickness over exygen band.

C. - Oxygen absorption for unit oxygen content.

C, - Si matrix absorption per unit thickness over 630/610 cm 1 band

C3 - Carbon absorption per unit concentration over 630/610 cm 1 band

C. - Si metriz absorption per unit thickness ever 610/395 cm 1 band

Cs - Carbon absorption per unit concentration over 610/595 cm l band

T . Thickness of reference sample

AT . Thickness difference between reference and sample

10) - Oxygen concentration of sample

[C] - Carbon concentration of sample

Note: the reference is assumed to have negligible carbon and oxygen.

Constants  $C_0$ - $C_5$  are obtained using standards with known enygon and carbon centent. The results described later used two standards, one 1.91 cm thick and containing no detectable enygon or carbon and one 1.905 cm thick containing 7.7 x  $10^{16}$  stem cm<sup>-3</sup> carbon and 0.92 x  $10^{16}$  stem cm<sup>-3</sup> oxygon (old ASTM calibration). Scans were cade of the pure standard using air as a reference and then of the impure standard using the pure standard as a reference. Using this data equations 3.1, 3.2 and 3.3 were solved for  $C_0$ - $C_5$ .

To determine the oxygen and carbon content and thickness of unknown samples equations 3.2 and 3.3 were solved for 57 and [C]. Equation 3.1 was then solved for [O]. This avoids the necessity of accounting the sample thickness by a separate technique. An incidental advantage is that if equation 2.2 or 2.4 is used to convert transmittance to shoorbance the errors introduced by the approximations involved tend to cancel cost other when the oxygen or carbon contentrations are evaluated. That is the thickness estimates tend to show more error than either the oxygen or carbon content.

#### 4 CHANG PITTING METHOD

The IR spectrum is seasoned 1300-1000 cm<sup>-1</sup> and 640-360 cm<sup>-1</sup> (or as required). The 640/360 band data is processed to give the thickness and carbon content. The 1200/1000 cm<sup>-1</sup> band spectra is then used to determine the oxygen content. Linear baselines (in absorbance) are assumed for both bands. All calculations are performed in absorbance units.

# 4.1 Amalysis

for the oxygen post

$$A_1(a_1) + a_0 + a_1a_1 + a_2a_1(a_1) + a_2a_2(a_1) + a_1$$
 (4.1)

and for the carbon soul

$$\Delta_2(x_i) = a_i + a_5 x_i + a_7 F_{21}(x_i) + a_6 F_{22}(x_i) + a_6$$
 (4.2)

shere

 $\mathbf{A}_{i}(\mathbf{x}_{j})$  - absorbance difference between sample and reference

x - Nevenumber - offset

and a linear baseline terms

a, . Difference in thickness between sample and reference

a; . Orygon in comple - orygon in reference

\* linear baseline terms

a. . Carbon in cample - Carbon in reference

F<sub>11</sub> - Silicon absorption over empte band

F<sub>12</sub> • Oxygen absorption

721 - Silicon absorption over earbon band

F<sub>22</sub> • Carbon absorption over carbon band

ti - randon notes

The vergnanter effect to choose to give the origin of the mid-point of each bond. For a legat equates fit we wish to minimise

$$\sum_{i} (a_{i}(a_{i}) - a_{i} - a_{i}a_{i} - a_{i}a_{i}(a_{i}) - a_{i}a_{i}(a_{i}))^{2}$$
(4.3)

with respect to ap. a. and a., and also

$$\sum_{i} (a_i) - a_i - a_j - a_j - a_j t_{21}(a_i) - a_j t_{22}(a_i))^2$$
(4.4)

with respect to  $a_2$ ,  $a_4$ ,  $a_5$ ,  $a_6$ . Note that only the 640/300  ${\rm cs}^{-1}$  band data is used to obtain the thickness estimate. This is because the 640/300  ${\rm cs}^{-1}$  band is most extensity dependent on the thickness of the susple and changes in the shape of the suppose pash due to best treatment etc night cause spurious results if the 1200/1000  ${\rm cs}^{-1}$  band data were included in the estimation of  $a_2$ .

As shown in section 4.2,  $P_{pk}(x_i)$  has the property

$$\sum_{i} F_{jk}(x_i) = 0 \tag{4.5}$$

$$\sum_{i} u_{i} F_{jk}(u_{i}) = 0 \qquad (4.6)$$

Minimiseries of 4.3 and 4.4 then gives:

$$a_2 = (s_1 s_2 - s_3 s_4)/(s_5 s_2 - s_4^2)$$
 (4.7)

$$a_{b} = (s_{1}s_{4} - s_{3}s_{5})/(s_{4}^{2} - s_{5}s_{6})$$
 (4.6)

$$a_3 = (S_7 - a_2 S_6)/S_6$$
 (4.9)

ووعف

$$s_1 - \sum r_{21}(s_1) \cdot s_2(s_1)$$

$$s_2 \cdot \sum r_{21}(a_1)^2$$

thautes the thickness, oxygen and curbon content of the reference the thickness, oxygen and curbon content of the sample may are be found.

# 4.2 Creation of Retailors

Two standard complex are used. Spectra are recorded of one using on air reference, then the difference spectra are annually. Conditions should be chosen so that the spectra may be treated as solar five.

$$\theta_1(a_1) = \theta_0 + \theta_1 + e_1 + \theta_0 \theta_{11}(a_1) + \theta_0 \theta_{12}(a_1)$$
 (4.10)

$$b_2(a_1) - b_2 - b_3 a_1 - b_6 + p_1(a_2) + b_1 p_2(a_2)$$
 (4.11)

$$b_3(a_1) - b_4 + b_5 a_1 - b_{11}b_{11}(a_1) + b_{12}b_{12}(a_1)$$
 (4.12)

$$B_{a}(a_{1}) = b_{1} + b_{2} + b_{12}P_{21}(a_{1}) + b_{12}P_{22}(a_{2})$$
 (4.13)

where a = b = are baseline terms

b = is the thickness of standard |

b = is the empen centent of standard |

b = is the carbon centent of standard |

b = is the carbon centent of standard |

b = is the thickness difference between standards | and |

b = is the empen difference between standards | and |

b = is the carbon difference between standards | and |

b = is the carbon difference between standards | and |

b = is the spectro in absorbance units |

To fix the baseline terms rather than pick arbitrary values for  $b_p = b_q$  as instead define the baselines such that

$$\sum_{i} F_{ij} (a_{i} a_{i} + 0) \qquad (6.34)$$

$$\sum_{i} c_{i,j} c_{i,j} c_{i,j} = 0 \qquad (4.33)$$

Equations 4:10 to 4:13 mm to solved for  $f_{11}(x_0)$  ,

#### 1 200.25

The performance of both archaels depends on the esquiracy ofth which the collibration to corridor out and instrument conditions used. It has been found that the cost satisfactory procedure to to use two standards, will appeal to thickness and one containing a high level of corbon and oxygen. Our normal archael to to use any reference standard 1.710 as thick out containing 0.91 a  $10^{10}$  often as  $^{1.9}$  output or exygen and one standard 1.700 as thick and containing 0.91 a  $10^{10}$  often as  $^{1.9}$  engine and  $^{1.7}$  a  $10^{10}$  often as  $^{1.9}$  curbon (as decorated using the old siffs without). First the reference is scannel against att, than the C2 standard is exemist against the reference. This procedure abulations errors introduced by institutions drift etc.

With suitable instrumental conditions (see below), when using the curve fitting arthur and using numbers by 2 as sell policies samples support accounts and reproducible to better than  $\frac{1}{2}$  3 and carbon to  $\frac{1}{2}$  165  $\frac{1}{2}$  2 3  $10^{35}$  storm  $^{2}$ . For 350 up device quality unders, where as six reference arthur is used arrors are about  $\frac{1}{2}$  165 for oxygen and  $\frac{1}{2}$  2 2  $10^{36}$  stop as  $^{3}$  for carbon. First than for accountaint and calculation is about 8 also if both carbon and support analysis is required.

# 5.1 Milest of flit Width

Theories for the integrated area measurement and also the curve fitting method both rely on the assumption that Boors law applies. Boors law may fail for a number of resease. One of the most common causes is that the finite shit width any cause breadening of the packs. Although, in the case of a single peak is is possible to construct a calibration curve and so correct for deviations from Boors law, this is not possible in the case of overlapping bands. Tooks vere therefore carried out to determine at what resolution desartures from Boors law linearity became a problem. Difference execute were recorded from five semiles nationally 2 on thick and covering a rense of carbon contents using a 2 am reference. The assets a ware almah averaged to reduce the noise to an instantificant level. The data were then enalysed using the curve fifting program. As the sift width the reduced the apparent carbon content of each cample approached a limiting value. Table I summarises the results. The percentage difference between the apparent carbon as assoured at 2 cm<sup>21</sup> resolvtion and at various other alit widths is shown. It can be seen that inadequate resolution leads to large errors in the apparent carbon content at law carbon levels. A resolution of 5.5 m<sup>-1</sup> (corresponding to 188 4 on the PE3003) 16 advancte to provide and foors for linearity. This is a much lover resolution then that required by PT mechines (reference 2) probably due to the very different testroment functions. The carges band to very auch breader than the carbon band and lif to portate office to use thath greater shift width. Constably to use a resolution of short 7 cm<sup>-1</sup> ( 1992 ) which is quite educate to ensure and facts has literarity. If currows shit widths are used than interference frience are observed to the spectro of som valors. In the case of the onyque character encourance both curve fitting and belometed ever trebule everage greet external friences and so those page as tool problem. With the worker discretion the interference frings are attornated by the strong absorption due to the 610 co. 1 hand.

# 3.3 Michaele Manutch fertrem femble auf finfreimer

Errors any arise to the apparent curbon content (and to a legacy extent the argum content) which are caused by abstacle to thickness between sample and reference. These any arise both from conditionarities in the spectrometer and also look of unusualitar stability. To assess these errors three samples, contently 2 on thick were ensured using references of differing thickness and also with an reference present. These as reference was used a reference team

attenuator, set to 545 T, use used to provide correction for reflection terms allowed for during conversion of transmittance to absorbance. Results are shown in table 2 which shows very good agreement both between integrated area and curve fitting methods and also insensitivity to thickness mismatch between sample and reference.

# 5.3 Major Massurements

Assess int of the curve fitting arthod for assurances on vafors was carried out using vafore 350 up neginal thickness with resistivities between 10 and 30 few out from boom positions in ingets. The actual oxygen and carbon contents of the vafore were estimated by linear interpolation from assourcements and on 3 as employ out at intervals along the ingets. When asking ansourcements of vafors it was found that under some conditions beats formed between interference fringes to the sample and reference spectre. Those beats could cause erroneous results and so for all the assourcements on vafors no reference is used. To expure proper conversion of transmittance to absorbance a reference beam attenuator set to \$42 T is used instead of the reference. As before all videts was choose so so to be a maximum consistent with Boors law linearity is to give a resolution of 7 as for the engages band ( 1982 ) and 5.5 on for carbon.

Table 3 above results of associations and using the curve fitting program on 10 values with characterity polithed both surfaces. The limits over which the curve fitting was unde were 1130/1600  $m^{-1}$  and 040/300  $m^{-1}$ . As discussed below the scan limits may affect the accuracy of the arthod. Mafer 2 was out from a region to which the anyon content in the crystal varied rapidly and so the actual argum content is uncertain. The spectra of values 4 and 2 showed no obvious reason for their pour performance. As any be seen from the table the accounted argum contents agree to about 72 with the actual value and the earlies to about  $\pm 1 \pm 10^{10}$  atom  $m^{-2}$ .

To escene the effects of back surface damps voters out adjacent to voters and vare tapped with 400 enery to produce severe damps. The oxygen and carbon contents were determined using the curve fitting arthod over the range 1200/1000 m<sup>-1</sup> and 640/300 m<sup>-1</sup>. In all cases the back damped vaters appeared to contain some oxygen than their characterity exched counterport (table 4). Changing the algorithm used to convert transmittance to absorbance to correspond with the

assumption that there was no multiple reflection inside the wafer (equation 2.4) gave no significant improvement (table 4). A detailed comparison was made between the fitted spectra and the actual spectra of one of the back damaged wafers. This is shown in figure 2, where it may be seen that systematic errors exist between the fitted and actual spectra. To investigate these errors further a spectrum was created to correspond to the best fit which could be made to the spectrum using the actual oxygen content of the wafer. This is shown in figure 3 compared to the actual spectrum. Also shown in figure 3 is the difference spectrum which represents the residuals. It may be seen that these follow a smooth curve showing that there is curvature of the baseline. To reduce this source of error it was found most convenient to reduce the limits over which the data is fitted to 1130/1080 cm<sup>-1</sup>. As shown in table 5 this greatly reduces the systematic errors associated with the back damaged wafers whilst retaining the accuracy of the measurements for the chemically polished wafers.

in table 6 data for wafers have been analysed using both curve fitting and integrated area methods. The integrated area method results used equation 2-4 to convert transmittance to absorbance while the curve fitting method uses equation 2-5. The integrated area measurements for oxygen are systematically 5% low primarily because of the approximation used to convert transmittance to absorbance.

# 5.4 Best Treated Samples

then Cz silicon is heat treated precipitates of crystabolite and amorphous  $\sin \theta_2$  are formed. These precipitates give rise to absorptions at 1225 cm<sup>-1</sup>, 1120 cm<sup>-1</sup> and 1080 cm<sup>-1</sup> which overlap the 1106 cm<sup>-1</sup> interstitial oxygen band. As a result, when measurements of the interstitial oxygen are made using the 1106 cm<sup>-1</sup> peak, problems arise in drawing a suitable base line. With the curve fitting method the baseline is fitted using data from all the spectral band being enamined. This makes the method much less sensitive to interference from overlapping bands. To test the method a set of 2 mm thick samples with oxygen essents in the range 1.3 - 1.5 x  $10^{18}$  atom cm<sup>-3</sup> (ASTN P121-76) and carbon contexts of 2-4 x  $10^{16}$  atom cm<sup>-1</sup> (ASTN F123-74) were prepared and isothermally ammedled in the range  $650^{\circ}$ C -  $1050^{\circ}$ C. Figure 4 shows examples of the spectra. In addition to the absorption at 1106 cm<sup>-1</sup> interstitial oxygen gives rise to a band at 515 cm<sup>-1</sup>. Shimura et al have shown that this absorption is due to

unclustered interstitial oxygen. This band suffers very much less from overlap with precipitate bands. It is not often used for quantitative measurement since it is much less intense than the 1106 cm band and its narrow half-width make it unsuitable for wafer measurements where interference fringes would cause severe problems. For well characterised 2mm samples the 515 cm<sup>-1</sup> band may be used as a measure of the interstitial oxygen. In figures 5(a) and 6(a) the interstitial oxygen content measured by the peak height at 1106 cm is compared to that determined from the 515 cm<sup>-1</sup> band. It may be seen that in the highly precipitated samples the apparent interstitial oxygen content is everestimated by about 3 x 10<sup>17</sup> atom cm<sup>-1</sup>. This is due to the underlying precipitate absorptions. When the data were analysed using the curve fitting method in the range 1130/1080 cm<sup>-1</sup> (figure 5(b) and 6(b)) very good agreement was found measurement with no sign of systematic error for all anneals below 1000°C. The 1050°C annealed samples showed some sign of systematic error. This is thought to be due to a change in shape of the 1106 cm band due to peiring of the oxygen atoms as distinct from true precipitation. This is discussed more fully by Shimura et al (3).

The results on the heat treated samples show that the curve fitting method is very well suited to making measurements on spectra where the band of interest is superimposed on interfering bands of unknown shape.

#### 6 CONCLUSION

Both curve fitting and integrated area measurements may be used to determine the oxygen and carbon content of device quality wafers. It is important to restrict the limits over which the spectra are analysed or systematic errors may be found in back damaged wafers. Instrument resolution is found to affect the accuracy of carbon measurement. The optimum resulution is a compranise between the effects of noise and interference fringes and Beers have non-limearity. Although the optimum conditions will vary between instruments the following conditions have been found to give satisfactory results:

### Integrated Area method:

Baseline: 1130/1120 and 1090/1080 for oxygen

: 640/630 and 595/580 for carbon

Peak Area: 1120/1090 cm<sup>-1</sup> for oxygen

630/610 cm<sup>-1</sup> for silicon + carbon 610/595 cm<sup>-1</sup> for carbon + silicon

In both cases the scan speed should be chosen to give the desired compromise between accuracy and analysis time.

#### **ACKNOWLEDGEMENTS**

I am grateful to W P Brown and the Materials Department at Mullards Southampton for the preparation of the wafers and heat treated material used in this study.

#### REFERENCES

- (1) Determination of Oxygen Concentration in Silicon and Germanium by Infrared Absorption. W Thurber, NBS Technical Note 529 (May 1970).
- (2) D Warren-Vidrine Anal. Chem. (1980) <u>52</u>, 92-96.
- (3) Fumio Shimura, Yoshitake Ohnishi, Hideki Tsuya, Appl. Phys. Lett. (1981) 38, 867.

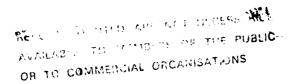


TABLE 1
NON LINEARITIES DUE TO INSTRUMENT RESOLUTION

CARBON AT 2 cm <sup>-1</sup> RESOLUTION	7 ERROR 4 cm <sup>-1</sup>	AT RESOLUT:	ION SHOWN
$3.5 \times 10^{16}$	-3	3	43
4.3 x 10 <sup>16</sup>	<b>-</b> 5	o	33
5.5 x 10 <sup>16</sup>	o	0	2
8.4 x 10 <sup>16</sup>	5	4	- 9
10.6 x 10 <sup>16</sup>	o	1	7
	}		

TABLE 2

EFFECT OF REFERENCE THICKNESS WITH 2mm NOMINAL THICKNESS SAMPLES

# a Integrated Area Method

	Peak	Upper Baseline	Lower Baseline
Oxygen Silicon + Carbon Carbon + Silicon	1125/1090	1180/1145	1065/1030
	626/612	648/632	607/602
	607/602	648/632	607/602

	( <b>x</b> 10 <sup>1</sup>	Oxygen 18 atom	cm <sup>-3</sup> )	(x10 <sup>16</sup>	Carbon	_		Thicknes	38
Sample	Refere	nce Thi	ckness 0	Refere	nce Th 2.000	ickness O	Refere	nce Thi 2.000	ckness 0
≠2 ≠14 ≠29	1.67 1.33 .85	1.67 1.32 .84	1.69 1.35 .86	3.2 5.2 13.1	3.6 5.4 13.2	2.5 4.9 12.2	1.931 1.975 1.963	1.939 1.985 1.971	1.924 1.964 1.949

# b <u>Curve Fitting Method</u>

Oxygen band: 1180/1030 cm<sup>-1</sup>
Carbon band: 640/580 cm<sup>-1</sup>

	(x10 <sup>1</sup>	Oxygen 8 atom o	·m <sup>-3</sup> )	(x10 <sup>1</sup>	Carbon 6	cm <sup>-3</sup> )	T	hicknes (mm)	s
Sample	I	nce Thic	ckness 0	Refere	nce Thi 2.000	ckness 0	Refere	nce Thi 2.000	ckness 0
#2 #14 #29	1.67 1.33 .85	1.66 1.32 .84	1.68 1.34 .86	3.4 5.2 13.2	3.7 5.5 13.3	2.5 5.0 12.4	1.931 1.977 1.965	1.940 1.987 1.976	1.934 1.974 1.960

TABLE 3
CURVE FITTING METHOD ON WAFERS

Scan Limits 1130/1080 cm<sup>-1</sup> and 640/580 cm<sup>-1</sup> Reference Beam - Attenuator set to 54%. All Wafers Chem Polished.

WAPER	ACTUAL OXYGEN × 10 <sup>18</sup>	MEASURED OXYGEN atom cm <sup>-3</sup>	ACTUAL CARBON × 10 <sup>16</sup>	MEASURED CARBON atom cm	ACTUAL THICKNESS	MEASURED THICKNESS	TRANSMISSION
A	1.81	1.80	1.4	2.9	360	347	Н
В	1.59	1.57	2.1	3.0	338	331	н
С	1.47	1.43	2.8	2.7	364	306	н
D	1.29	1.33	3.9	4.1	364	348	н
E	1.2*	1.12	6.0	6.6	339	328	H
F	1.61	1.55	4.0	4.4	364	370	м
G	1.47	1.49	5.0	5.0	369	357	н
н	1.38	1.10	7.8	6.9	338	361	н
1	1.71	1.65	3.0	2.8	351	338	H
J	1.53	1.43	4.0	2.0	372	409	L
ĸ	1.40	1.31	5.0	4.5	359	349	H
L	1.30	1.27	6.8	7.8	364	353	н
М	1.18	1.19	13.4	9.9	377	371	н
N	1.78	1.68	.4	.4	340	336	н
0	1.57	1.51	.7	1.1	342	332	н
P	1.39	1.40	1.2	1.5	343	339	В
Q	1.20	1.18	1.9	1.8	348	348	н
R	1.10	1.28	3.9	3.9	368	365	H

H = 100Z - 50Z transmission

M = 50% - 20% transmission

L = 20% - 10% transmission

VL = <10% transmission

TABLE 4

EFFECT OF BACK SURFACE DAMAGE

	LEGO .	OXTGEN (x 10 <sup>18</sup> )	<b>S</b>		CARBON (x 10 <sup>16</sup> )	016)		TRICORSS (LA)	<u> </u>	TRANSMISSION
SWELL	ACTUAL	BQH 2.5	BQH 2.4	ACTUAL	EQH 2.5	EQH 2.4	ACTUAL	EQW 2.5	EQH 2.4	
∢	1.81	1.79	1.79	1.4	2.9	2.9	8	347	387	=
٠,	1.81	2.01	2.01	1.4	2.4	2.5	354	355	355	4
•	1.59	1.58	1.61	2.1	3.0	3.0	338	331	375	23
'n	1.59	1.89	1.89	2.1	1.4	1.5	328	332	333	4
ပ	1.47	1.4	1.46	2.8	2.7	2.7	312	Š	346	15
ບ	1.47	1.83	1.82	2.8	2.4	2.4	311	312	313	4
۵	1.29	1.34	1.30	3.9	4.1	4.2	*	348	376	<b>8</b>
ò	1.29	1.59	1.56	3.9	3.8	3.8	339	<b>X</b>	¥	ي
M	1.2	1.12	1.11	6.0	9.9	5.6	339	328	¥	gai
M	1.2	1.52	1.52	0.9	2.6	9.9	311	321	321	4
	_				;					

Nefers A', B', C', D', E' have back surface demage Scan limits are  $1200/1000~{\rm cm}^{-1}$  and  $640/580~{\rm cm}^{-1}$ 

Messurements were made using both equations 2.5 and 2.4 to convert transmittance to absorbance.

TABLE 5

EFFECT OF SCAN LIMITS ON OXYGEN HEASUREMENT

	ACTUAL	MEASURE	O OXYGEX
SAIPLE	OXYGEN	1200/1000 cm <sup>-1</sup>	1130/1000 cm <sup>-1</sup>
A	1.81 = 10 <sup>18</sup>	1.79 x 10 <sup>18</sup>	1.80 x 10 <sup>18</sup>
<b>A</b> *	1.81 × 10 <sup>18</sup>	2.01 × 10 <sup>18</sup>	1.79 × 10 <sup>18</sup>
3	1.59 × 10 <sup>18</sup>	1.58 × 10 <sup>18</sup>	1.57 x 10 <sup>18</sup>
3'	1.59 × 10 <sup>18</sup>	1.09 x 10 <sup>18</sup>	1.58 × 10 <sup>18</sup>
С	1.47 x 10 <sup>18</sup>	1.44 × 10 <sup>18</sup>	1.43 x 10 <sup>18</sup>
c'	1.47 x 10 <sup>18</sup>	1.83 × 10 <sup>18</sup>	1.49 x 10 <sup>18</sup>
D	1.29 x 10 <sup>18</sup>	1.34 × 10 <sup>18</sup>	1.33 x 10 <sup>18</sup>
ים	1.29 × 10 <sup>18</sup>	1.59 x 10 <sup>18</sup>	1.39 x 10 <sup>18</sup>
8	1.2 x 10 <sup>18</sup>	1.12 x 10 <sup>18</sup>	1.12 x 10 <sup>18</sup>
E'	1.2 x 10 <sup>16</sup>	1.52 x 10 <sup>18</sup>	1.26 x 10 <sup>18</sup>

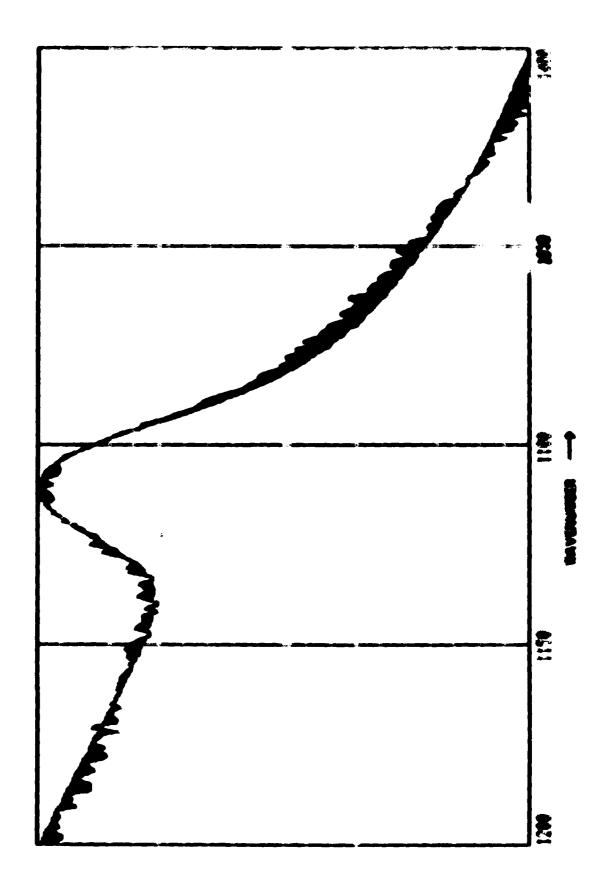
CONSACTOR SETTEMENT INTRODUCTO AMEA AND CORNE PTETTING NETTERS

	orross (s 10 <sup>1</sup>	otes cs.3	CARBON (s. 10 <sup>18</sup>	4. m m m	TELCORES	3
	Integrated Area	Carre Pitting	Integrated Area	Piccia.	Integrated Area	Area Pitting
•	1.6	1.8	3.0	2.0	82	×
*	3:	2:	4.2	2.4	3	333
•	8.	1.57	7.4	3.0	â	2
•	1.47	2:	2.2	1.4	â	ac
v	1.8	1.43	3.1	2.7	3	ž
່	7.1	<b>::</b>	1.1	2.4	Ä	æ
•	1.71	<b>1.8</b>	3.0	4.1	2	3
'n	1.31	2.3	••	3.0	X.	Z
•	3.	1.12	7.1	•;	2	*
<b>:</b>	1.21	2:	2.0	2.0	Z	æ
			_	-	_	

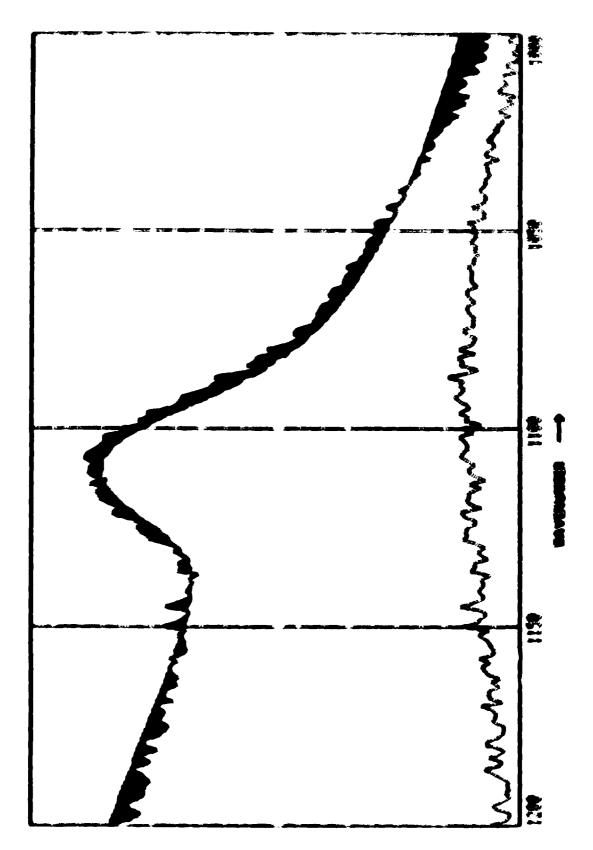
Integrated area limits: Describe 1130/1130; 10f0/1060 and 640/630; 993/360

Stilices Pest 1130/1070 cm<sup>-1</sup> Stilices Pest 630/ 610 cm<sup>-1</sup> Cartes Pest 610/ 555 cm<sup>-1</sup> Curve fitting method limits: 1130/1080 and 440/980 cm-1

The integrated area method uses equation 2.4 to convert transmittance to absorbance and the curve fitting method equation 2.5.



71000 2 Heavard spectra for water D' compared to best fit curve. The difference between the two curves is sheded.



PIGGE 3 Record spectra for unfor D' compared to spectrum extendated from actual oxygen contest. (The difference between the two spectra is shaded.) Lower curve shows difference spectra which represents residuals.

